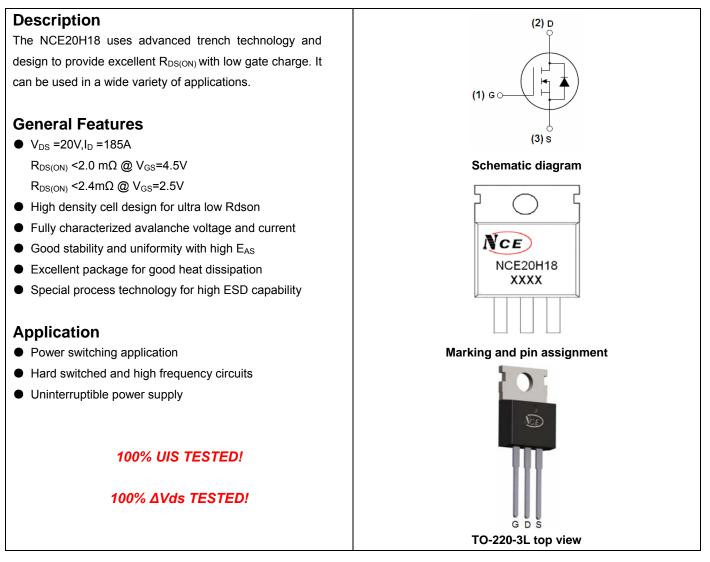


# NCE N-Channel Enhancement Mode Power MOSFET



## Package Marking and Ordering Information

| Device Marking | Device   | Device Package | Reel Size | Tape width | Quantity |
|----------------|----------|----------------|-----------|------------|----------|
| NCE30H15       | NCE30H15 | TO-220-3L      | -         | -          | -        |

#### Absolute Maximum Ratings (T<sub>c</sub>=25<sup>°</sup>C unless otherwise noted)

| Parameter                                      | Symbol                | Limit | Unit |
|--|-----------------------|-------|------|
| Drain-Source Voltage                           | Vds                   | 20    | V    |
| Gate-Source Voltage                            | Vgs                   | ±12   | V    |
| Drain Current-Continuous                       | Ι <sub>D</sub>        | 185   | Α    |
| Drain Current-Continuous(T <sub>C</sub> =100℃) | I <sub>D</sub> (100℃) | 130   | А    |
| Pulsed Drain Current                           | I <sub>DM</sub>       | 400   | A    |
| Maximum Power Dissipation                      | PD                    | 130   | W    |
| Derating factor                                |                       | 0.87  | W/°C |
| Single pulse avalanche energy (Note 5)         | E <sub>AS</sub>       | 1700  | mJ   |





NCE20H18

| Operating Junction and Storage Temperature Range | T <sub>J</sub> ,T <sub>STG</sub> | -55 To 175 | °C |
|--|----------------------------------|------------|----|

## **Thermal Characteristic**

| Thermal Resistance, Junction-to-Case <sup>(Note 2)</sup> | R <sub>0JC</sub> | 1.15 | °C <b>/W</b> |
|--|------------------|------|--------------|

#### Electrical Characteristics (T<sub>c</sub>=25<sup>°</sup>C unless otherwise noted)

| Parameter                          | Symbol              | Symbol Condition  |     | Тур  | Max  | Unit |  |
|------------------------------------|---------------------|---|-----|------|------|------|--|
| Off Characteristics                |                     |   | •   |      |      |      |  |
| Drain-Source Breakdown Voltage     | BV <sub>DSS</sub>   | V <sub>GS</sub> =0V I <sub>D</sub> =250µA                           | 20  | -    | -    | V    |  |
| Zero Gate Voltage Drain Current    | I <sub>DSS</sub>    | V <sub>DS</sub> =20V,V <sub>GS</sub> =0V                            | -   | -    | 1    | μA   |  |
| Gate-Body Leakage Current          | I <sub>GSS</sub>    | V <sub>GS</sub> =±12V,V <sub>DS</sub> =0V                           | -   | -    | ±100 | nA   |  |
| On Characteristics (Note 3)        |                     |   | •   |      |      |      |  |
| Gate Threshold Voltage             | V <sub>GS(th)</sub> | V <sub>DS</sub> =V <sub>GS</sub> ,I <sub>D</sub> =250µA             | 0.5 | 0.75 | 1.2  | V    |  |
|                                    |                     | V <sub>GS</sub> =4.5V, I <sub>D</sub> =20A                          | -   | 1.4  | 2.0  | mΩ   |  |
| Drain-Source On-State Resistance   | R <sub>DS(ON)</sub> | V <sub>GS</sub> =2.5V, I <sub>D</sub> =15A                          |     | 1.6  | 2.4  |      |  |
| Forward Transconductance           | <b>g</b> fs         | V <sub>DS</sub> =5V,I <sub>D</sub> =20A                             | 100 | -    | -    | S    |  |
| Dynamic Characteristics (Note4)    |                     |   |     |      |      | L    |  |
| Input Capacitance                  | C <sub>lss</sub>    |   | -   | 5000 | -    | PF   |  |
| Output Capacitance                 | C <sub>oss</sub>    | - V <sub>DS</sub> =10V,V <sub>GS</sub> =0V,                         | -   | 1200 | -    | PF   |  |
| Reverse Transfer Capacitance       | C <sub>rss</sub>    | F=1.0MHz  | -   | 900  | -    | PF   |  |
| Switching Characteristics (Note 4) |                     |   | •   |      |      |      |  |
| Turn-on Delay Time                 | t <sub>d(on)</sub>  |   | -   | 12   | -    | nS   |  |
| Turn-on Rise Time                  | tr                  | $V_{DD}$ =10V, $I_D$ =2A, $R_L$ =15 $\Omega$                        | -   | 13   | -    | nS   |  |
| Turn-Off Delay Time                | t <sub>d(off)</sub> | V <sub>GS</sub> =10V,R <sub>G</sub> =2.5Ω                           | -   | 45   | -    | nS   |  |
| Turn-Off Fall Time                 | t <sub>f</sub>      |   | -   | 32   | -    | nS   |  |
| Total Gate Charge                  | Qg                  | N/ 40X/1 00A  | -   | 70   |      | nC   |  |
| Gate-Source Charge                 | Q <sub>gs</sub>     | $V_{DS}$ =10V,I <sub>D</sub> =20A,                                  | -   | 16   |      | nC   |  |
| Gate-Drain Charge                  | Q <sub>gd</sub>     | V <sub>GS</sub> =10V  | -   | 20   |      | nC   |  |
| Drain-Source Diode Characteristics |                     |   | •   |      |      |      |  |
| Diode Forward Voltage (Note 3)     | V <sub>SD</sub>     | V <sub>GS</sub> =0V,I <sub>S</sub> =20A                             | -   |      | 1.2  | V    |  |
| Diode Forward Current (Note 2)     | Is                  |   | -   | -    | 150  | А    |  |
| Reverse Recovery Time              | t <sub>rr</sub>     | TJ = 25°C, IF = 20A   | -   | 49   | -    | nS   |  |
| Reverse Recovery Charge            | Qrr                 | di/dt = 100A/µs <sup>(Note3)</sup>                                  | -   | 66   | -    | nC   |  |
| Forward Turn-On Time               | t <sub>on</sub>     | Intrinsic turn-on time is negligible (turn-on is dominated by LS+LE |     |      |      |      |  |

#### Notes:

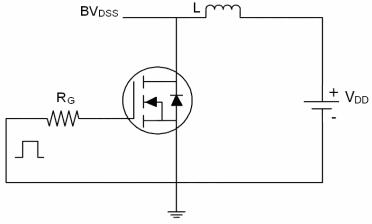
- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- **2.** Surface Mounted on FR4 Board,  $t \le 10$  sec.
- **3.** Pulse Test: Pulse Width  $\leq$  300µs, Duty Cycle  $\leq$  2%.
- 4. Guaranteed by design, not subject to production
- **5.**  $E_{AS}$  condition : Tj=25°C,  $V_{DD}$ =20V,  $V_{G}$ =10V, L=1mH, Rg=25 $\Omega$ ,  $I_{AS}$ =58.5A



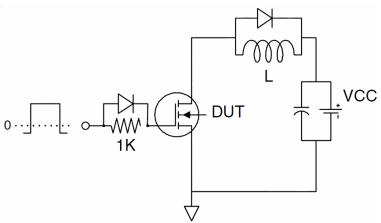




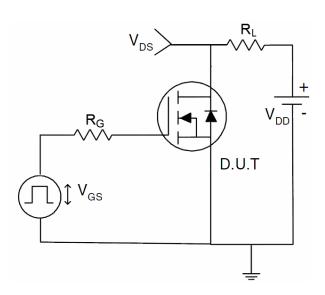
## Test circuit 1) E<sub>AS</sub> Test Circuit



## 2) Gate Charge Test Circuit



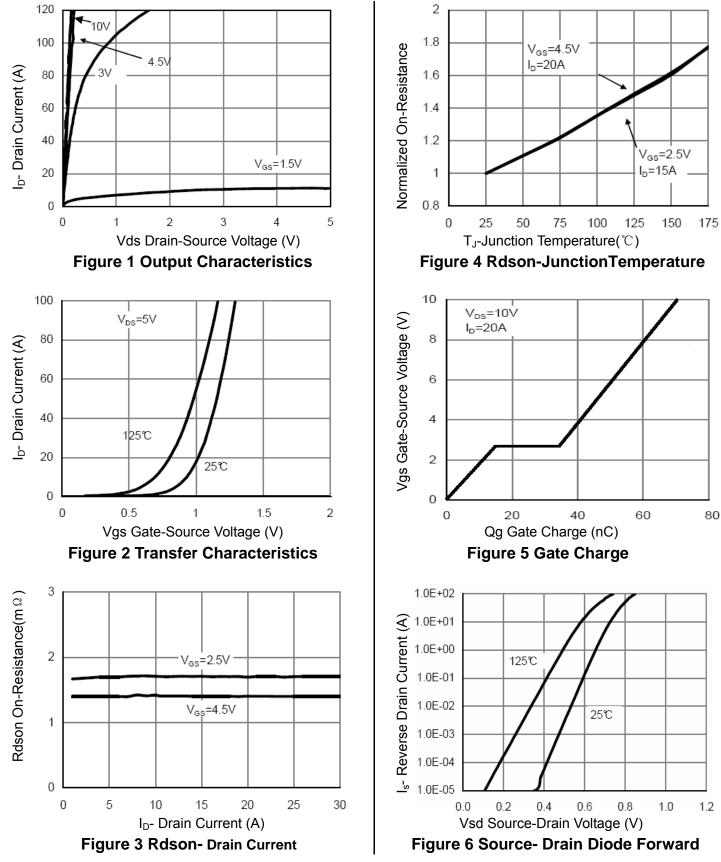
3) Switch Time Test Circuit









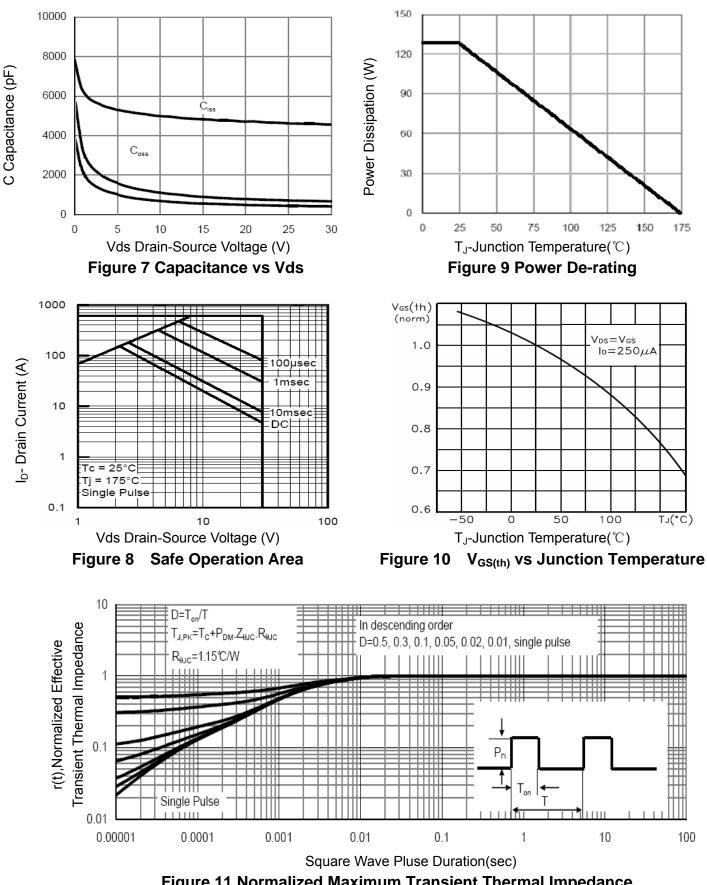




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**NCE20H18** 





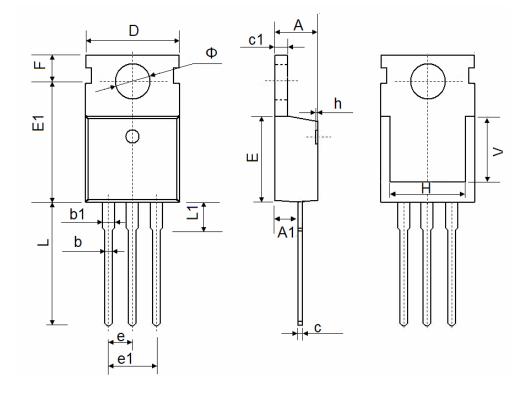


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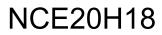
## TO-220-3L Package Information



| Symbol | Dimensions | s In Millimeters | Dimension  | s In Inches |
|--------|------------|------------------|------------|-------------|
|        | Min.       | Max.             | Min.       | Max.        |
| А      | 4.400      | 4.600            | 0.173      | 0.181       |
| A1     | 2.250      | 2.550            | 0.089      | 0.100       |
| b      | 0.710      | 0.910            | 0.028      | 0.036       |
| b1     | 1.170      | 1.370            | 0.046      | 0.054       |
| С      | 0.330      | 0.650            | 0.013      | 0.026       |
| c1     | 1.200      | 1.400            | 0.047      | 0.055       |
| D      | 9.910      | 10.250           | 0.390      | 0.404       |
| E      | 8.9500     | 9.750            | 0.352      | 0.384       |
| E1     | 12.650     | 12.950           | 0.498      | 0.510       |
| е      | 2.540 TYP. |                  | 0.100 TYP. |             |
| e1     | 4.980      | 5.180            | 0.196      | 0.204       |
| F      | 2.650      | 2.950            | 0.104      | 0.116       |
| Н      | 7.900      | 8.100            | 0.311      | 0.319       |
| h      | 0.000      | 0.300            | 0.000      | 0.012       |
| L      | 12.900     | 13.400           | 0.508      | 0.528       |
| L1     | 2.850      | 3.250            | 0.112      | 0.128       |
| V      | 7.500 REF. |                  | 0.295      | REF.        |
| Φ      | 3.400      | 3.800            | 0.134      | 0.150       |







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